Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
Between 1.022 inches and 1.253 inches
Function For Which Designed:
Rectifier
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-4
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Threaded stud
Features Provided:
Reverse polarity
Overall Width Across Flats:
Between 0.424 inches and 0.437 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
150.0 reverse voltage, instantaneous and 150.0 working peak reverse voltage
Current Rating Per Characteristic:
20.00 amperes forward current, average absolute
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 1 tab, solder lug
Specification Data:
53711-6321601-4 manufacturers specification control
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0